General Purpose Transistor (Isolated Dual Transistors) EMT1/UMT1N/IMT1A

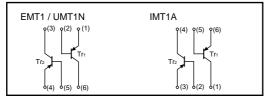
Features

- 1) Two 2SA1037AK chips in a EMT or UMT or SMT package.
- 2) Mounting possible with EMT3 or UMT3 or SMT3 automatic mounting machines.
- 3) Transistor elements are independent, eliminating interference.

Structure

Epitaxial planar type PNP silicon transistor

Equivalent circuit



The following characteristics apply to both $\ensuremath{\text{Tr}}\xspace_1$ and $\ensuremath{\text{Tr}}\xspace_2$.

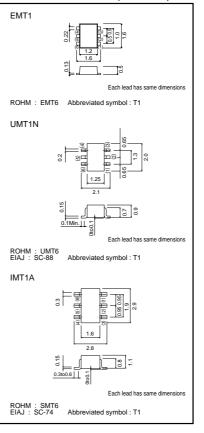
●Absolute maximum ratings (Ta = 25°C)

		• •	,				
Pa	arameter	Symbol	Limits	Unit			
Collector-base voltage		Vсво	-60	V			
Collector-emitter voltage		Vceo	-50	V			
Emitter-base voltage		Vево	-6	V			
Collector current		lc	-150	mA			
Collector power dissipation	EMT1, UMT1N	Pc	150 (TOTAL)	mW *1 *2			
	IMT1A	PC	300 (TOTAL)				
Junction temperature		Tj	150	°C			
Storage temperature		Tstg	-55 to +150	°C			

*1 120mW per element must not be exceeded.

*2 200mW per element must not be exceeded.

•External dimensions (Unit : mm)



Transistors

•Electrical characteristics (Ta = 25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions	
Collector-base breakdown voltage	ВУсво	-60	-	-	V	Ic = -50μA	
Collector-emitter breakdown voltage	BVCEO	-50	-	-	V	Ic = -1mA	
Emitter-base breakdown voltage	ВУево	-6	-	-	V	Ιε = -50μΑ	
Collector cutoff current	Ісво	-	-	-0.1	μA	Vcb = -60V	
Emitter cutoff current	Іево	-	-	-0.1	μA	$V_{EB} = -6V$	
Collector-emitter saturation voltage	VCE(sat)	-	-	-0.5	V	$Ic/I_B = -50mA/-5mA$	
DC current transfer ratio	hfe	120	-	560	-	$V_{CE} = -6V$, $I_C = -1mA$	
Transition frequency	fт	-	140	-	MHz	Vce = -12V, Ie = 2mA, f = 100MHz	
Output capacitance	Cob	-	4	5	pF	Vсв = -12V, IE = 0A, f = 1MHz	

Packaging specifications

	Package	Taping			
	Code	T2R	TR	T108	
Туре	Basic ordering unit (pieces)	8000	3000	3000	
EMT1		0	-	-	
UMT1N		-	0	-	
IMT1A		-	-	0	

Electrical characteristic curves

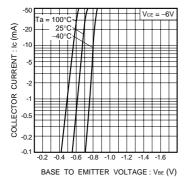
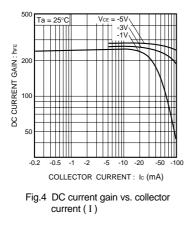
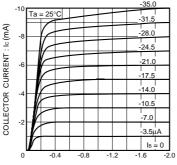


Fig.1 Grounded emitter propagation characteristics





COLLECTOR TO EMITTER VOLTAGE : $V_{CE}(V)$

Fig.2 Grounded emitter output characteristics (I)

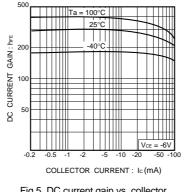
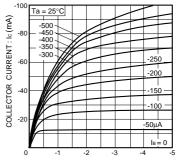


Fig.5 DC current gain vs. collector current (II)



COLLECTOR TO EMITTER VOLTAGE : VCE (V)

Fig.3 Grounded emitter output characteristics (II)

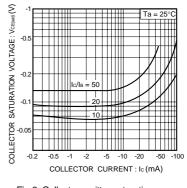


Fig.6 Collector-emitter saturation voltage vs. collector current (I)

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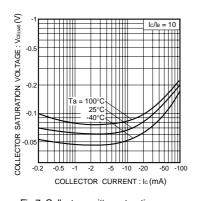


Fig.7 Collector-emitter saturation voltage vs. collector current (II)

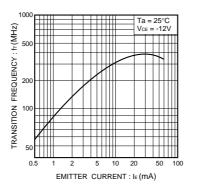
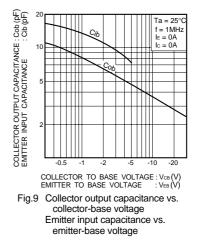


Fig.8 Gain bandwidth product vs. emitter current



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